TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

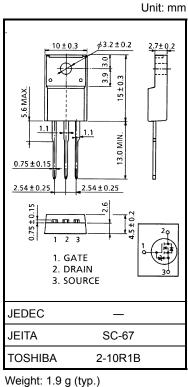
# 2SK3310

#### Switching Regulator Applications

- Low drain-source ON resistance:  $R_{DS (ON)} = 0.48 \Omega$  (typ.) ٠
- High forward transfer admittance:  $|Y_{fs}| = 4.3 \text{ S}$  (typ.) •
- Low leakage current: I<sub>DSS</sub> = 100 µA (max) (V<sub>DS</sub> = 450 V)
- Enhancement model: V<sub>th</sub> = 3.0 to 5.0 V (V<sub>DS</sub> = 10 V, I<sub>D</sub> = 1 mA) •

#### Absolute Maximum Ratings (Ta = 25°C)

| Characte              | eristics                 | Symbol           | Rating     | Unit |  |
|-----------------------|--------------------------|------------------|------------|------|--|
| Drain-source voltage  | <u>}</u>                 | V <sub>DSS</sub> | 450        | V    |  |
| Drain-gate voltage (F | R <sub>GS</sub> = 20 kΩ) | VDGR             | 450        | V    |  |
| Gate-source voltage   |                          | V <sub>GSS</sub> | ±30        | V    |  |
| Drain current         | DC (Note 1)              | ۱ <sub>D</sub>   | 10         | А    |  |
|                       | Pulse (Note 1)           | I <sub>DP</sub>  | 40         | А    |  |
| Drain power dissipat  | ion (Tc = 25°C)          | PD               | 40         | W    |  |
| Single pulse avalance | he energy<br>(Note 2)    | E <sub>AR</sub>  | 222        | mJ   |  |
| Avalanche current     |                          | I <sub>AR</sub>  | 10         | А    |  |
| Repetitive avalanche  | energy (Note 3)          | E <sub>AR</sub>  | 4          | mJ   |  |
| Channel temperature   | 9                        | T <sub>ch</sub>  | 150        | °C   |  |
| Storage temperature   | range                    | T <sub>stg</sub> | –55 to 150 | °C   |  |



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

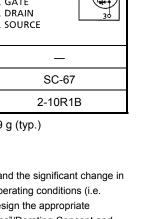
| Characteristics                        | Symbol                 | Max   | Unit |  |
|--|------------------------|-------|------|--|
| Thermal resistance, channel to case    | R <sub>th (ch-c)</sub> | 3.125 | °C/W |  |
| Thermal resistance, channel to ambient | R <sub>th (ch-a)</sub> | 62.5  | °C/W |  |

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:  $V_{DD} = 90 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial), L = 3.7 mH,  $R_G = 25 \Omega$ ,  $I_{AR} = 10 \text{ A}$ 

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.



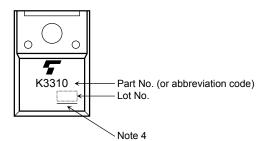
**Electrical Characteristics (Ta = 25°C)** 

| Chara                        | cteristics     | Symbol               | Test Condition  | Min | Тур. | Max  | Unit |
|------------------------------|----------------|----------------------|---|-----|------|------|------|
| Gate leakage current         |                | I <sub>GSS</sub>     | $V_{GS}=\pm 25~V,~V_{DS}=0~V$   |     |      | ±10  | μA   |
| Gate -source brea            | akdown voltage | V (BR) GSS           | $I_G=\pm 10~\mu A,~V_{DS}=0~V$  | ±30 |      |      | V    |
| Drain cut-off curre          | ent            | I <sub>DSS</sub>     | $V_{DS} = 450 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$  |     |      | 100  | μA   |
| Drain-source brea            | kdown voltage  | V (BR) DSS           | $I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$   | 450 | _    |      | V    |
| Gate threshold vo            | Itage          | V <sub>th</sub>      | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$   | 3.0 |      | 5.0  | V    |
| Drain-source ON              | resistance     | R <sub>DS (ON)</sub> | $V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$  |     | 0.48 | 0.65 | Ω    |
| Forward transfer a           | admittance     | Y <sub>fs</sub>      | $V_{DS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$  | 1.5 | 4.3  |      | S    |
| Input capacitance            |                | C <sub>iss</sub>     | $V_{DS}$ = 25 V, $V_{GS}$ = 0 V, f = 1 MHz  |     | 920  |      | pF   |
| Reverse transfer capacitance |                | C <sub>rss</sub>     |   |     | 12   |      |      |
| Output capacitance           |                | C <sub>oss</sub>     | ]   |     | 140  |      |      |
| Switching time               | Rise time      | tr                   | $V_{GS}^{10 V}$ $V_{GS}^{10 V}$ $V_{GS}^{10 V}$ $V_{DU}^{10 V}$ | _   | 25   | _    | • ns |
|                              | Turn-on time   | t <sub>on</sub>      |   |     | 35   |      |      |
|                              | Fall time      | tf                   |   | _   | 10   | _    |      |
|                              | Turn-off time  | toff                 |   | _   | 60   | _    |      |
| Total gate charge            |                | Qg                   |   | _   | 23   |      | nC   |
| Gate-source charge           |                | Q <sub>gs</sub>      | $V_{DD} \simeq 360$ V, $V_{GS} = 10$ V, $I_D = 10$ A  |     | 9    |      |      |
| Gate-drain charge            |                | Q <sub>gd</sub>      | 1   |     | 14   |      |      |

### Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics                           | Symbol           | Test Condition                                 | Min | Тур. | Max  | Unit |
|---|------------------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I <sub>DR</sub>  | —  | _   | _    | 10   | А    |
| Pulse drain reverse current (Note 1)      | I <sub>DRP</sub> | —  | _   | _    | 40   | А    |
| Forward voltage (diode)                   | V <sub>DSF</sub> | $I_{DR} = 10 \text{ A}, V_{GS} = 0 \text{ V}$  | _   | _    | -1.7 | V    |
| Reverse recovery time                     | trr              | $I_{DR} = 10 \text{ A}, V_{GS} = 0 \text{ V},$ | _   | 280  | _    | ns   |
| Reverse recovery charge                   | Q <sub>rr</sub>  | $dI_{DR}/dt = 100 \text{ A}/\mu\text{s}$       |     | 2.7  |      | μC   |

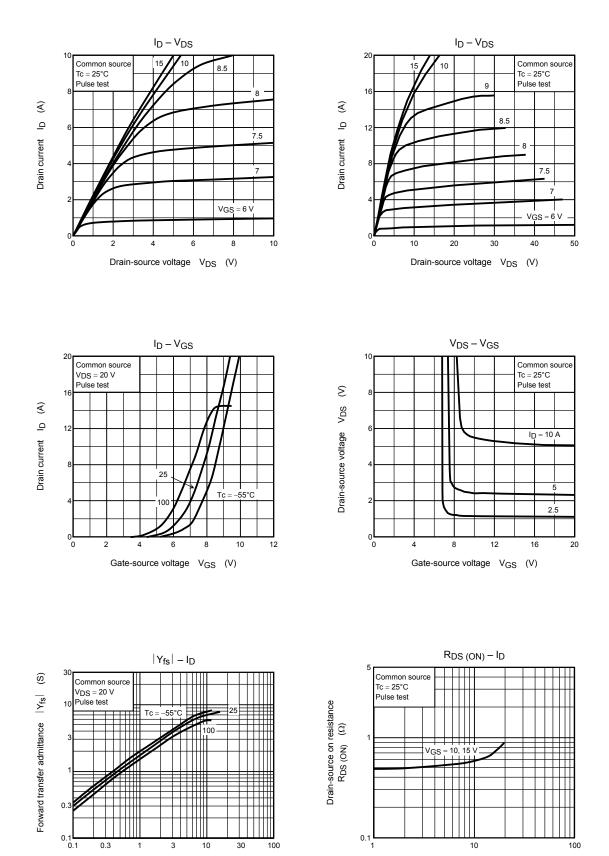
## Marking



Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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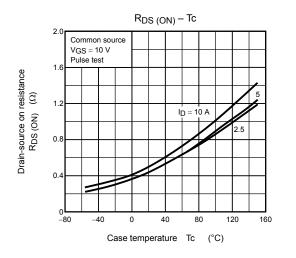
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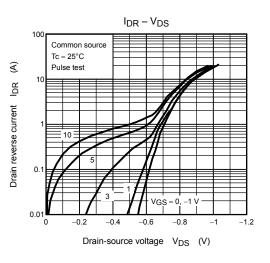


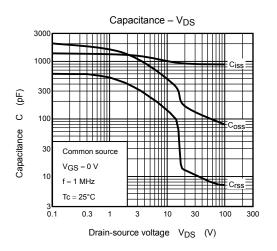
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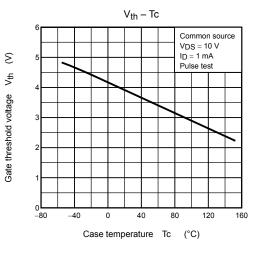
Drain current ID (A)

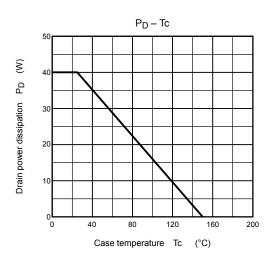
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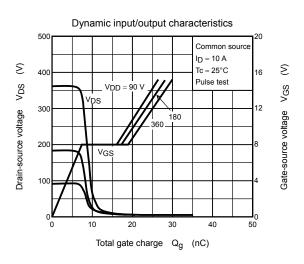


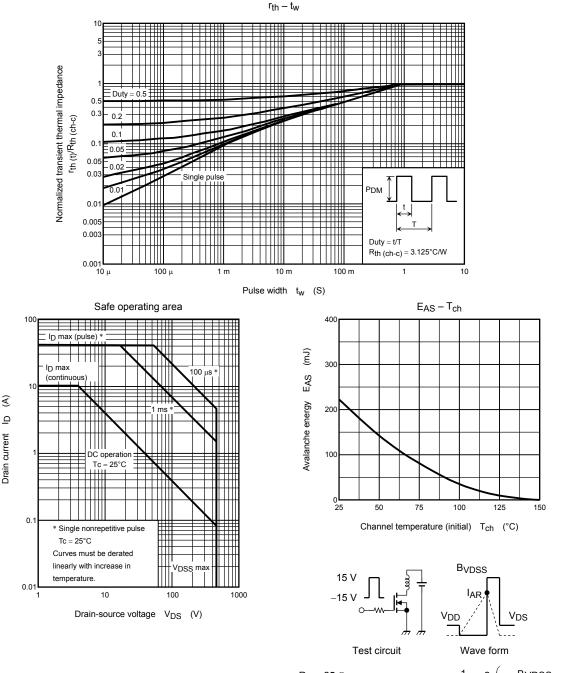












 $\begin{array}{l} \mathsf{R}_{G} = 25 \; \Omega \\ \mathsf{V}_{DD} = 90 \; \mathsf{V}, \; \mathsf{L} = 3.7 \; \mathsf{m} \mathsf{H} \end{array} \qquad \mathsf{E}_{AS} = \frac{1}{2} \cdot \mathsf{L} \cdot \mathsf{I}^{2} \cdot \left( \frac{\mathsf{B}_{VDSS}}{\mathsf{B}_{VDSS} - \mathsf{V}_{DD}} \right) \end{array}$ 

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